Unit: mm

TOSHIBA Transistor Silicon PNP Triple Diffused Type

# 2SA2120

### **Power Amplifier Applications**

- Complementary to 2SC5948
- Recommended for audio frequency amplifier output stage.

### **Absolute Maximum Ratings (Tc = 25°C)**

Characteristic	Symbol	Rating	Unit
Collector-base voltage	VCBO	-200	V
Collector-emitter voltage	VCEO	-200	V
Emitter-base voltage	V <sub>EBO</sub>	-5	٧
Collector current	IC	-12	Α
Base current	ΙΒ	-1.2	Α
Collector power dissipation	PC	200	W
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

1. BASE 2. COLLECTOR (HEAT SINK) 3. EMITTER

JEDEC

JEITA

TOSHIBA

2.15.9MAX.

Ø3.2±0.2

0.7 Very 10.2

5.45±0.2

7. Very 10.2

8. Collector (HEAT SINK)

2.16C1A

Weight: 4.7 g (typ.)

Please design the appropriate reliability upon reviewing the

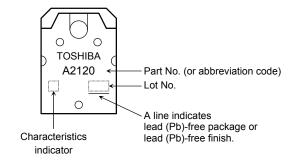
Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

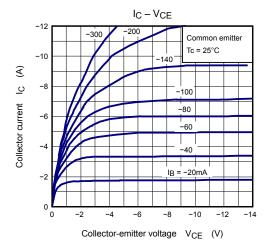
## Electrical Characteristics (Tc = 25°C)

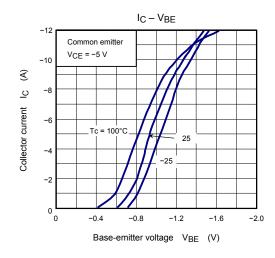
Characteristic	Symbol	Test Conditions	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -200 V, I <sub>E</sub> = 0	_	_	-5.0	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-5.0	μΑ
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -50 \text{ mA}, I_B = 0$	-200	-		٧
DC current gain	h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1 A	55	-	160	
	h <sub>FE (2)</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -7 A	35	80	_	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = -8 A, I <sub>B</sub> = -0.8 A	_	-1.5	-3.0	V
Base-emitter voltage	$V_{BE}$	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -7 A	_	-1.0	-1.5	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1 A	_	25	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz	_	470	_	pF

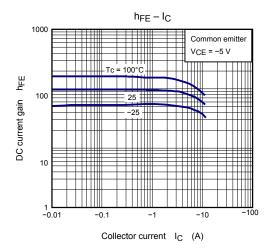
Note: hFE (1) classification R: 55~110, O: 80~160

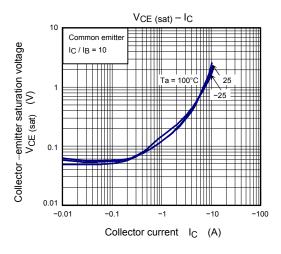
### Marking

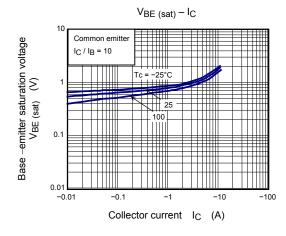


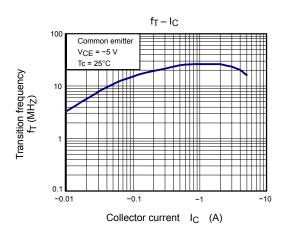




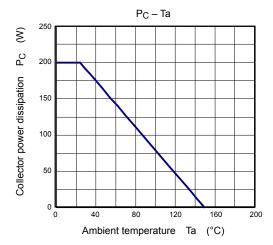


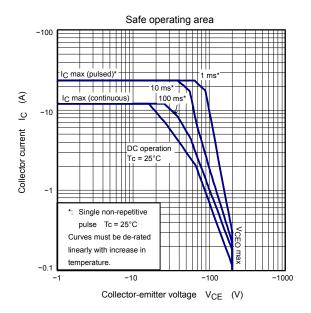


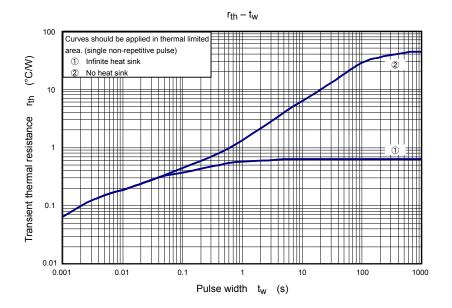




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